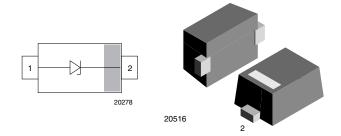
COMPLIANT

GREEN (5-2008)**



Vishay Semiconductors

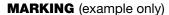
ESD-Protection Diode in SOD-923



FEATURES

- Single-line ESD-protection device
- ESD-immunity acc. IEC 61000-4-2
 20 kV contact discharge
 30 kV air discharge
- Tiny SOD-923 package
- Package height = 0.4 mm
- Typ. capacitance 12 pF (V_B = 2.5 V; f = 1 MHz)
- Leakage current $< 0.1 \mu A (V_R = 5 V)$

 Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC





Bar = cathode marking

X = date code

Y = type code (see table below)

ORDERING INFORMATION					
DEVICE NAME	E NAME ORDERING CODE		MINIMUM ORDER QUANTITY		
VESD05A1B-02Z	VESD05A1B-02Z-GS08	8000	8000		

PACKAGE DATA						
DEVICE NAME	PACKAGE NAME	TYPE CODE	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS
VESD05A1B-02Z	SOD-923	Н	0.45 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT		
Peak pulse current	acc. IEC 61000-4-5; t _P = 8/20 μs; single shot	I _{PPM}	3	Α		
Peak pulse power	acc. IEC 61000-4-5; $t_P = 8/20 \mu s$; single shot	P _{PP}	33	W		
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V _{ESD}	± 20	kV		
	Air discharge acc. IEC 61000-4-2; 10 pulses	V _{ESD}	± 30	kV		
Operating temperature	Junction temperature	TJ	- 40 to + 125	°C		
Storage temperature		T _{stg}	- 55 to + 150	°C		

^{**} Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

Vishay Semiconductors ESD-Protection Diode in SOD-923



ELECTRICAL CHARACTERISTICS VESD05A1B-02Z BIAS mode (between pin 1 and pin 2)							
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Protection paths	Number of lines which can be protected	N _{lines}	-	-	1	lines	
Reverse stand off voltage	at I _R = 0.1 μA	V_{RWM}	5	-	-	V	
Reverse current	at V _R = 5 V	I _R	-	0.01	0.1	μA	
Reverse breakdown voltage	at I _R = 1 mA	V_{BR}	6	6.8	7.5	V	
Reverse Clamping voltage	at I _{PP} = 1 A	V _C	-	8	9.5	V	
	at I _{PP} = I _{PPM} = 3 A	V _C	-	8.9	11	V	
Forward clamping voltage	at I _{PP} = 0.2 A	V_{F}	-	0.95	1.2	V	
	at I _{PP} = 1 A	V_{F}	-	1.3	-	V	
	at I _{PP} = I _{PPM} = 3 A	V_{F}	-	1.9	-	V	
Capacitance	at V _R = 0 V; f = 1 MHz	C _D	-	19	23	pF	
	at V _R = 2.5 V; f = 1 MHz	C _D	-	12	-	pF	

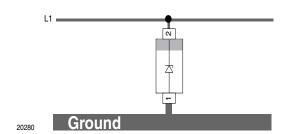
Note

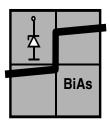
BIAS-MODE (BIDIRECTIONAL ASYMMETRICAL PROTECTION MODE)

With the **VESD05A1B-02Z** one signal- or data-lines (L1) can be protected against voltage transients. With pin 1 connected to ground and pin 2 connected to a signal- or data-line which has to be protected. As long as the voltage level on the data- or signal-line is between 0 V (ground level) and the specified **M**aximum **R**everse **W**orking **V**oltage (\mathbf{V}_{RWM}) the protection diode between data line and ground offers a high isolation to the ground line. The protection device behaves like an open switch. As soon as any positive transient voltage signal exceeds the break through voltage level of the protection diode, the diode becomes conductive and shorts the transient current to ground. Now the protection device behaves like a closed switch. The **C**lamping **V**oltage (\mathbf{V}_{C}) is defined by the **BR**eakthrough **V**oltage (\mathbf{V}_{BR}) level plus the voltage drop at the series impedance (resistance and inductance) of the protection device.

Any negative transient signal will be clamped accordingly. The negative transient current is flowing in the forward direction of the protection diode. The low Forward Voltage (V_F) clamps the negative transient close to the ground level.

Due to the different clamping levels in forward and reverse direction the **VESD05A1B-02Z** clamping behaviour is <u>Bi</u>directional and <u>Asymmetrical</u> (BiAs).





[•] Ratings at 25 °C, ambient temperature unless otherwise specified



ESD-Protection Diode in SOD-923 Vishay Semiconductors

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

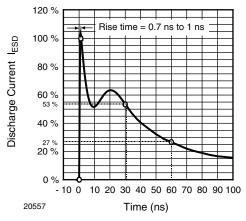


Fig. 1 - ESD Discharge Current Wave Form acc. IEC 61000-4-2 (330 $\Omega/150$ pF)

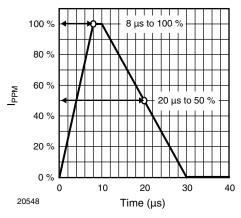


Fig. 2 - 8/20 µs Peak Pulse Current Wave Form acc. IEC 61000-4-5

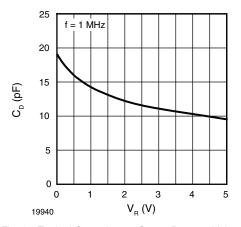


Fig. 3 - Typical Capacitance C_D vs. Reverse Voltage V_R

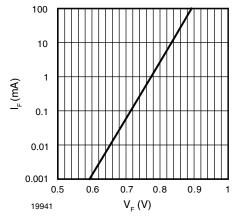


Fig. 4 - Typical Forward Current I_F vs. Forward Voltage V_F

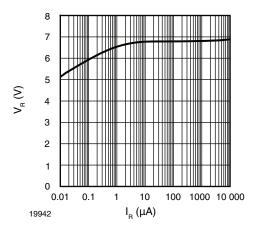


Fig. 5 - Typical Reverse Voltage V_R vs. Reverse Current I_R

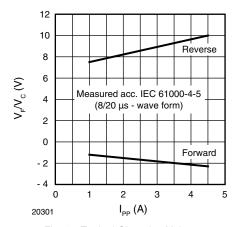


Fig. 6 - Typical Clamping Voltage vs. Peak Pulse Current I_{PP}

Vishay Semiconductors ESD-Protection Diode in SOD-923



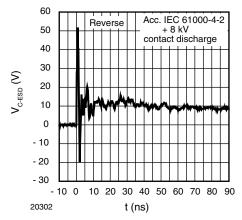


Fig. 7 - Typical Clamping Performance at + 8 kV Contact Discharge (acc. IEC 61000-4-2)

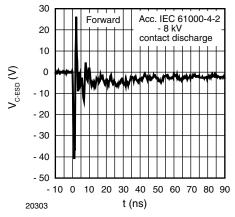


Fig. 8 - Typical Clamping Performance at - 8 kV Contact Discharge (acc. IEC 61000-4-2)

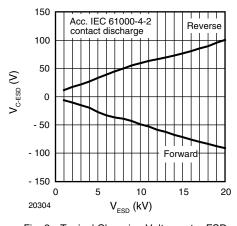
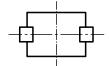


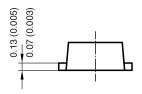
Fig. 9 - Typical Clamping Voltage at \pm ESD Contact Discharge (acc. IEC 61000-4-2)

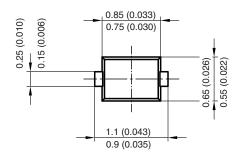


ESD-Protection Diode in SOD-923 Vishay Semiconductors

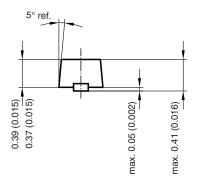
PACKAGE DIMENSIONS in millimeters (inches): SOD-923



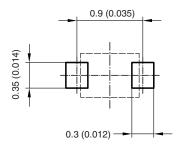




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Foot print recommendation:







Vishay

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